

General Purpose Transistors PNP Silicon

FEATURE

- Collector current capability $I_c = -500$ mA.
- Collector-emitter voltage $V_{CEO}(max) = -45 V$.
- General purpose switching and amplification.
- PNP complement: LBC807 Series.
- •We declare that the material of product compliance with RoHS requirements.
- S- Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.

DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Shipping
LBC807-25WT1G S-LBC807-25WT1G	5B	3000/Tape&Reel
LBC807-25WT3G S-LBC807-25WT3G	5B	10000/Tape&Reel

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MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector–Emitter Voltage	V _{CEO}	-45	V
Collector-Base Voltage	V _{CBO}	-50	V
Emitter–Base Voltage	V _{EBO}	-5.0	V
Collector Current — Continuous	Ι _c	-500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR- 5 Board (1)	PD	150	mW
T _A =25 °C			
Derate above 25°C		1.2	mW/°C
Thermal Resistance, Junction to Ambient	R _{BJA}	833	°C/W
Total Device Dissipation	PD	200	mW
Alumina Substrate, (2) $T_A = 25^{\circ}C$			
Derate above 25°C		1.6	mW/°C
Thermal Resistance, Junction to Ambient	R _{0JA}	625	°C/W
Junction and Storage Temperature	T_{J},T_{stg}	-55to+150	°C

1. FR–5 = $1.0 \times 0.75 \times 0.062$ in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



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ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

	Characteristic	Symbol	Min	Тур	Max	Unit			
o	OFF CHARACTERISTICS								
	Collector-Emitter Breakdown Voltage								
	(I _c = -10 mA)	V _{(BR)CEO}	-45	_	_	V			
	Collector-Emitter Breakdown Voltage								
	$(V_{EB} = 0, I_{C} = -10 \ \mu A)$	V(BR)CES	-50	_	—	V			
	Emitter-Base Breakdown Voltage								
	$(I_{E} = -1.0 \ \mu A)$	V(br)ebo	-5.0	—	—	V			
	Collector Cutoff Current	I _{CBO}							
	$(V_{CB} = -20 \text{ V})$		—	—	-100	nA			
	$(V_{CB} = -20 \text{ V}, \text{ T}_{J} = 150^{\circ}\text{C})$		_	_	-5.0	μA			

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

	Characteristic	Symbol	Min	Тур	Max	Unit
ON C	CHARACTERISTICS					
	DC Current Gain (I_c = -100 mA, V _{CE} = -1.0 V)	h _{FE}	160	_	400	_
	Collector–Emitter Saturation Voltage ($I_c = -500 \text{ mA}, I_B = -50 \text{ mA}$)	V _{CE(sat)}	_	_	-0.7	V
	Base–Emitter On Voltage ($I_c = -500 \text{ mA}, V_{ce} = -1.0 \text{ V}$)	V BE(on)	_	_	-1.2	V

SMALL-SIGNAL CHARACTERISTICS

Current–Gain — Bandwidth Product ($I_c = -10$ mA, $V_{CE} = -5.0$ V_{dc} , f = 100 MHz)	f _T	100	_	—	MHz
Output Capacitance ($V_{CB} = -10 \text{ V}, \text{ f} = 1.0 \text{ MHz}$)	C _{obo}	_	10	—	pF



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SC-70 (SOT-323)





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.90	1.00	0.032	0.035	0.040	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A2	0.7 REF			0.028 REF			
b	0.30	0.35	0.40	0.012	0.014	0.016	
С	0.10	0.18	0.25	0.004	0.007	0.010	
D	1.80	2.10	2.20	0.071	0.087		
Е	1.15	1.24	1.35	0.045 0.049 0.			
е	1.20 1.30 1.40		1.40	0.047	0.051	0.055	
e1	0.65 BSC			0.026 BSC			
L	0.425 REF			0.017 REF			
HE	2.00	2.10	2.40	0.079 0.083 0			

GENERIC MARKING DIAGRAM



XX M = Specific Device Code = Date Code -

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

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